

isc N-Channel MOSFET Transistor

IPA90R500C3, IIPA90R500C3

• FEATURES

- Drain-source on-resistance:
 R_{DS}(on) ≤ 0.5Ω@10V
- · Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



DESCRITION

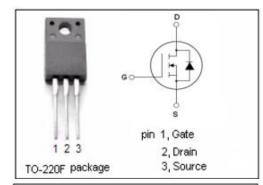
High fast switching Power Supply

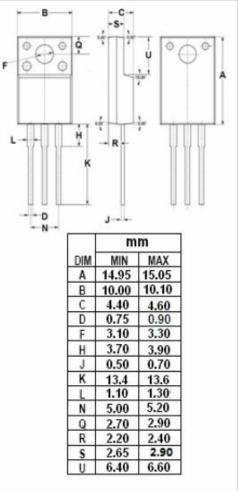
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	900	V	
V _{GS}	Gate-Source Voltage	±20	V	
I _D	Drain Current-Continuous	А		
I _{DM}	Drain Current-Single Pulsed 24		А	
P _D	Total Dissipation @T _C =25℃ 34		W	
Tj	Max. Operating Junction Temperature 150		${\mathbb C}$	
T _{stg}	Storage Temperature	-55~150	${\mathbb C}$	

• THERMAL CHARACTERISTICS

SYMBOL	YMBOL PARAMETER		UNIT					
Rth(ch-c)	Channel-to-case thermal resistance	3.7	°C/W					







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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 250 μ A	900			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =0.74mA	2.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =6.6A			0.5	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = 20V;V _{DS} = 0V			100	nA
Ibss	Drain-Source Leakage Current	V _{DS} =900V; V _{GS} = 0V			1	- μΑ
		V _{DS} =900V; V _{GS} = 0V;T _j =150°C		10		
V _{SD}	Diode forward voltage	I _{DR} =6.6A, V _{GS} = 0 V		0.9	1.2	V

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